

# SANYO Semiconductors DATA SHEET

# SCH2202 — NPN Epitaxial Planar Silicon Transistor Switching, Driver Applications

# **Applications**

· Low-frequency power amplifier, high-speed switch, motor drivers, muting.

## **Features**

- · Composite type with 2 NPN transistor contained in a single package, facilitating high-density mounting.
- Ultrasmall package permitting applied sets to be small and slim.
- · Small ON-resistance (Ron).

## **Specifications**

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		20	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		600	mA
Collector Current (Pulse)	ICP		1.2	Α
Collector Dissipation	PC	Mounted on a ceramic board (600mm <sup>2</sup> X0.8mm) 1unit	0.4	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ІСВО	V <sub>CB</sub> =15V, I <sub>E</sub> =0A			100	nA
Emitter Cutoff Current	IEBO	VEB=4V, IC=0A			100	nA
DC Current Gain	hFE	V <sub>CE</sub> =2V, I <sub>C</sub> =10mA	300		800	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =2V, I <sub>C</sub> =50mA		330		MHz
Output Capacitance	Cob	VCB=10V, f=1MHz		3.2		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =200mA, I <sub>B</sub> =10mA		150	300	mV
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	IC=200mA, IB=10mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0A	20			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0A	5			V

Marking: EF Continued on next page.

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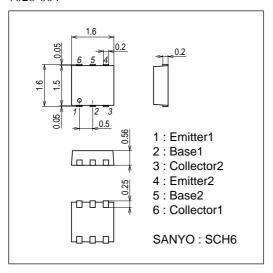
## **SCH2202**

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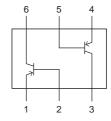
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turm-ON Time	ton	See specified test circuit.		30		ns
Storage Time	t <sub>stg</sub>	See specified test circuit.		77		ns
Fall Time	tf	See specified test circuit.		40		ns

## **Package Dimensions**

unit : mm 7028-004



## **Electrical Connection**



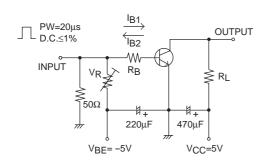
1 : Emitter1 2 : Base1

3 : Collector2 4 : Emitter2

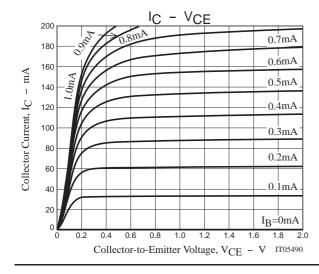
5 : Base2 6 : Collector1

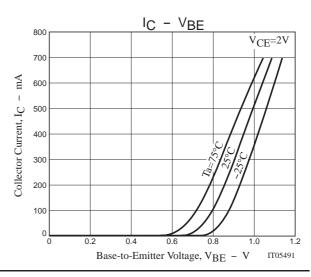
Top view

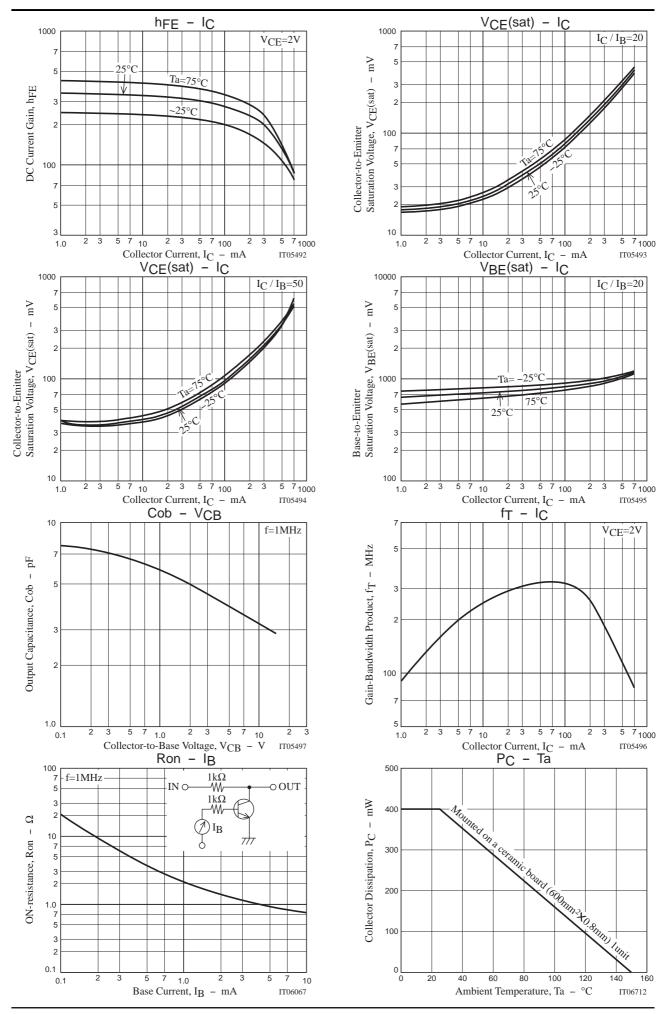
## **Switching Time Test Circuit**



$$I_{C}=20I_{B1}=-20I_{B2}=400mA$$







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